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SERIAL NUMBER 09/652,550	FILING DATE 08/31/2000 RULE	CLASS 438	GROUP ART UNIT 2811	ATTORNEY DOCKET NO. KM1-001	
APPLICANTS Keiji Jono, Kato-gun, JAPAN; Hirokazu Ueda, Kobe, JAPAN; Hiroyuki Watanabe, Nishiwaki, JAPAN;					
** CONTINUING DATA ***** ** FOREIGN APPLICATIONS *****					
IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 10/13/2000					
Foreign Priority claimed <input type="checkbox"/> yes <input checked="" type="checkbox"/> no 35 USC 119 (a-d) conditions met <input type="checkbox"/> yes <input checked="" type="checkbox"/> no <input type="checkbox"/> Met after Allowance Verified and Acknowledged	Examiner's Signature <i>Caues</i> Initials <i>qv</i>	STATE OR COUNTRY JAPAN	SHEETS DRAWING 3	TOTAL CLAIMS 61	INDEPENDENT CLAIMS 7
ADDRESS 021567 WELLS ST. JOHN P.S. 601 W. FIRST AVENUE, SUITE 1300 SPOKANE , WA 99201					
TITLE Methods of forming an isolation trench in a semiconductor, methods of forming an isolation trench in a surface of a silicon wafer, methods of forming an isolation trench-isolated transistor, trench-isolated transistor, trench isolation structures formed in a semiconductor, memory cells and DRAMs					
FILING FEE RECEIVED 2098	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue)		